NSN 5961-00-011-8208

No Fiig: A110a0



Transistor - Page 1 of 1 View Online at https://aerobasegroup.com/nsn/5961-00-011-8208 **Inclosure Material:** Metal **Overall Length:** 0.328 inches **Overall Diameter:** 0.875 inches **Mounting Facility Quantity:** 2 **Internal Configuration:** Junction contact **Electrode Internally-electrically Connected To Case:** Collector **Internal Junction Configuration:** Npn **Mounting Method:** Unthreaded hole **Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 500.0 collector to emitter voltage/static/base open and 700.0 collector to emitter voltage, dc with specified circuit between base and emitter and 5.0 emitter to base voltage, static, collector open **Current Rating Per Characteristic:** Between 2.00 amperes source cutoff current and 3.50 amperes collector current, dc **Power Rating Per Characteristic:** 100.0 watts total power dissipation **Maximum Operating Tempurature Per Measurement Point:** 150.0 degrees celsius junction **Terminal Type And Quantity:** 2 pin and 1 case Shelf Life: N/a **Unit Of Measure:** Demilitarization: